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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RQJ0602EGDQS

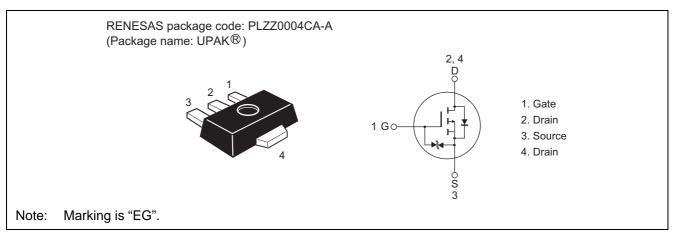
Silicon P Channel MOS FET Power Switching

REJ03G1268-0300 Rev.3.00 Jun 05, 2006

Features

- Low on-resistance $R_{DS(on)} = 485 \text{ m}\Omega \text{ typ } (V_{GS} = -10 \text{ V}, I_D = -0.75 \text{ A})$
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline



*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

			(Iu 25 C)
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	-60	V
Gate to source voltage	V _{GSS}	+10 / -20	V
Drain current	I _D	-1.5	А
Drain peak current	I _{D (pulse)} Note1	-2.2	А
Body - drain diode reverse drain current	I _{DR}	-1.5	А
Channel dissipation	Pch Note2	1.5	W
Channel dissipation	Pch (pulse) Note1	5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \le 1$ s, duty cycle $\le 1\%$

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)

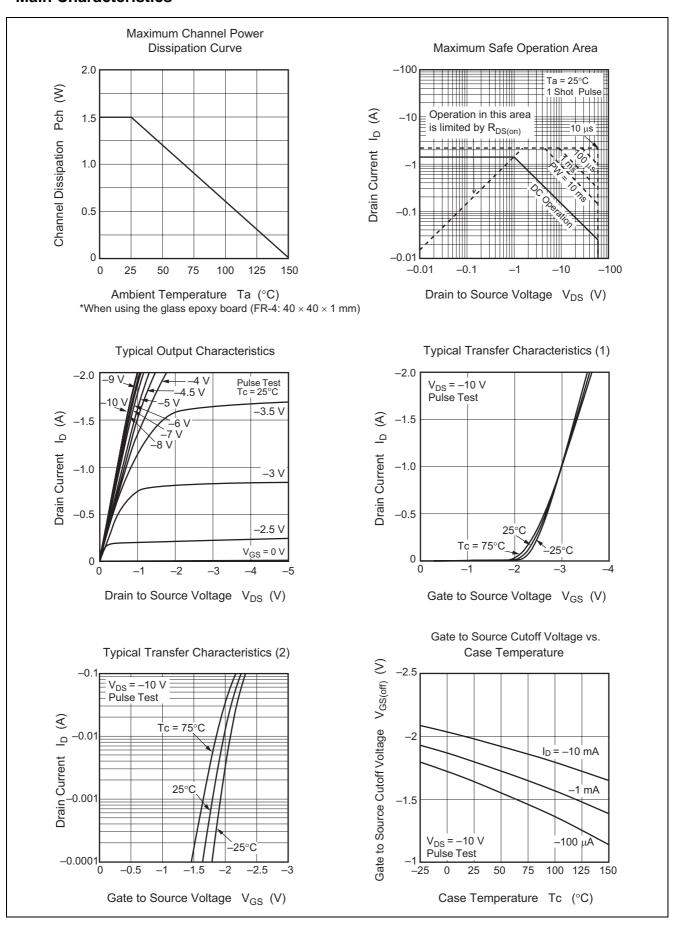
Electrical Characteristics

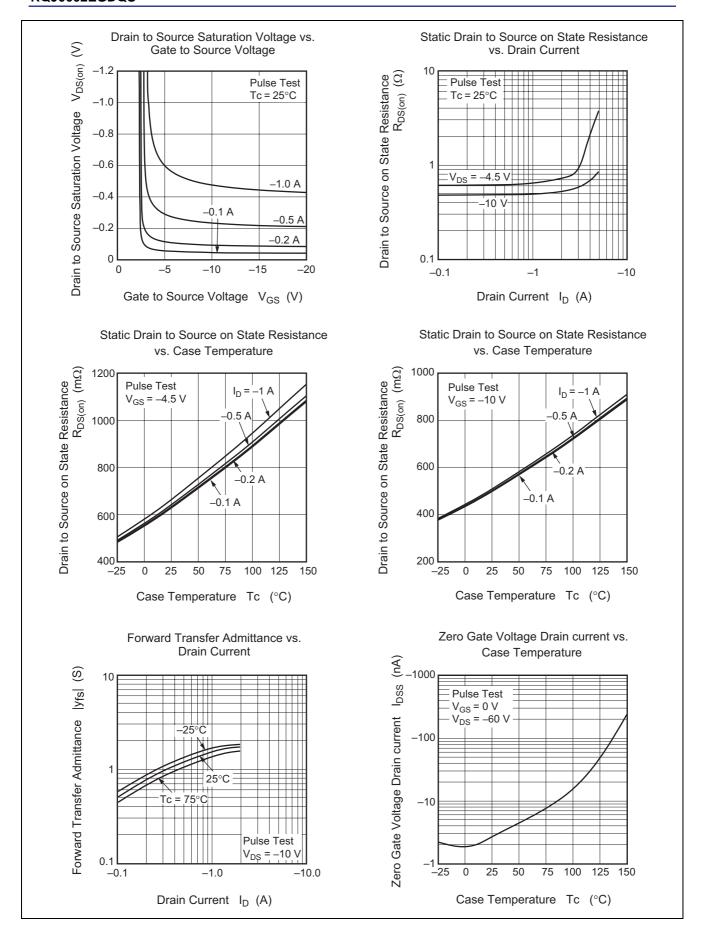
 $(Ta = 25^{\circ}C)$

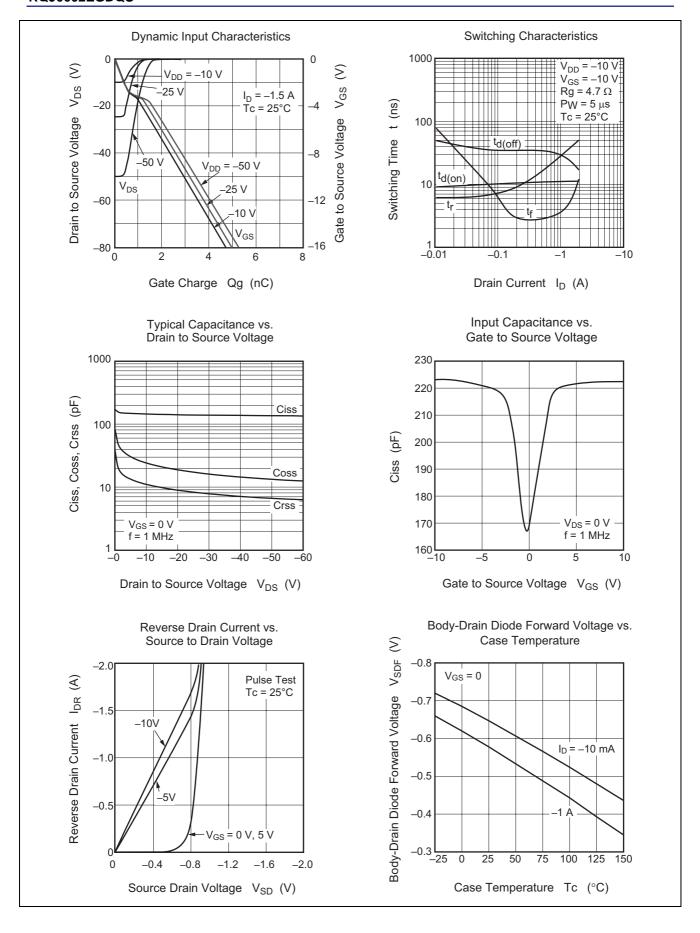
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+10	_	_	V	$I_G = +100 \mu A, V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-20	_		>	$I_G = -100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I _{GSS}		_	+10	μΑ	$V_{GS} = +8 \text{ V}, V_{DS} = 0$
Gate to source leak current	I _{GSS}		_	-10	μΑ	$V_{GS} = -16 \text{ V}, V_{DS} = 0$
Drain to source leak current	I _{DSS}		_	-1	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.0	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Drain to source on state resistance	R _{DS(on)}	_	485	607	mΩ	$I_D = -0.75 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note3}}$
	R _{DS(on)}	_	620	868	mΩ	$I_D = -0.75 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y _{fs}	0.8	1.4	_	S	$I_D = -0.75 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss	_	135	_	pF	V _{DS} = -10 V
Output capacitance	Coss	_	24	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	12	_	pF	f = 1 MHz
Turn - on delay time	t _{d(on)}	_	11	_	ns	$I_D = -1 A$
Rise time	t _r	_	28	_	ns	$V_{GS} = -10 \text{ V}$
Turn - off delay time	$t_{d(off)}$	_	29	_	ns	$R_L = 6.6 \Omega$
Fall time	t _f	_	3.6	_	ns	$Rg = 4.7 \Omega$
Total gate charge	Qg		2.9		nC	V _{DD} = −10 V
Gate to source charge	Qgs		0.6	_	nC	$V_{GS} = -10 \text{ V}$
Gate to drain charge	Qgd	_	0.3	_	nC	$I_D = -1.5 A$
Body - drain diode forward voltage	V_{DF}	_	-0.9	_	V	$I_F = -1.5 \text{ A}, V_{GS} = 0^{\text{Note3}}$

Notes: 3. Pulse test

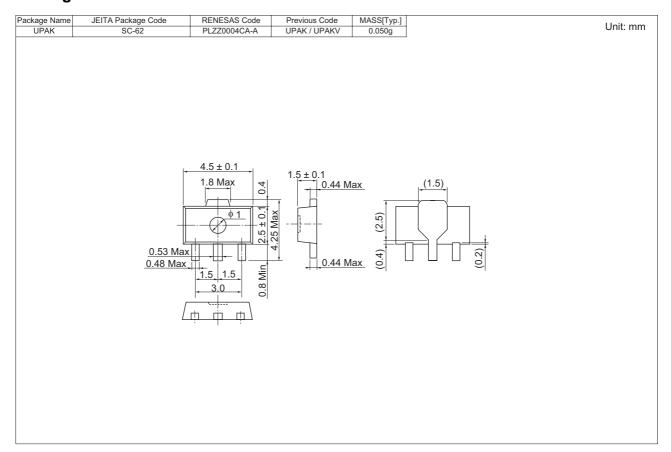
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
RQJ0602EGDQSTL-E	1000 pcs.	φ178 reel, 12 mm Emboss taping

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